

# M61533FP

## 4ch Electronic Volume with AGC

REJ03F0059-0100Z

Rev.1.0

Sep.19.2003

### Features

Function	Feature
Electric Volume	<ul style="list-style-type: none"> <li>• 0 to -87dB, <math>-\infty/1\text{dBstep}</math></li> <li>• 4ch SL/SR/C/SW independent Electric Volume</li> <li>• Controlled by trim volume data + master volume data.</li> </ul>
AGC	$V_c=1.8\text{Vrms} <\text{SWch}>$
LPF	Can be set externally $<\text{SWch}>$
Output Gain Control	0, +6, +9, +12dB 4step $<\text{SWch}>$
MUC I/F	Controlled by serial data from microcomputer

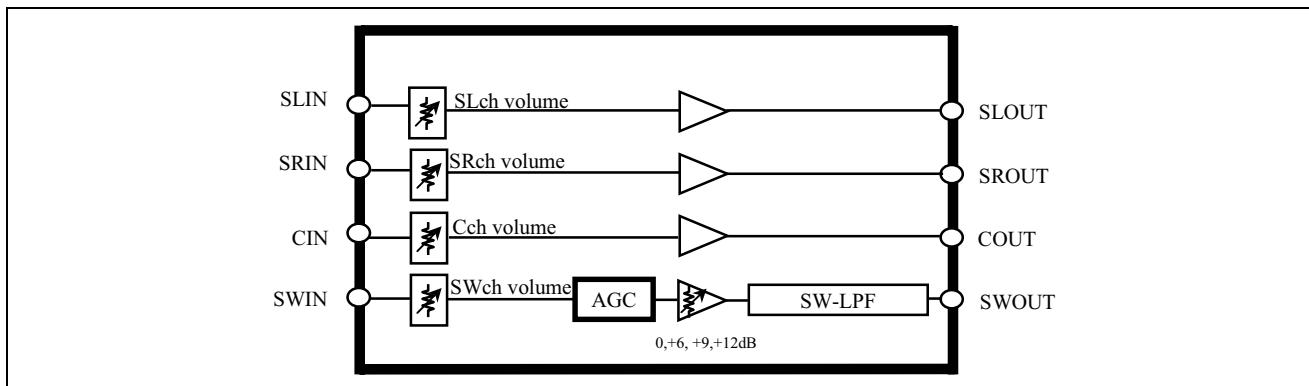
### Application

Mini Stereo etc.

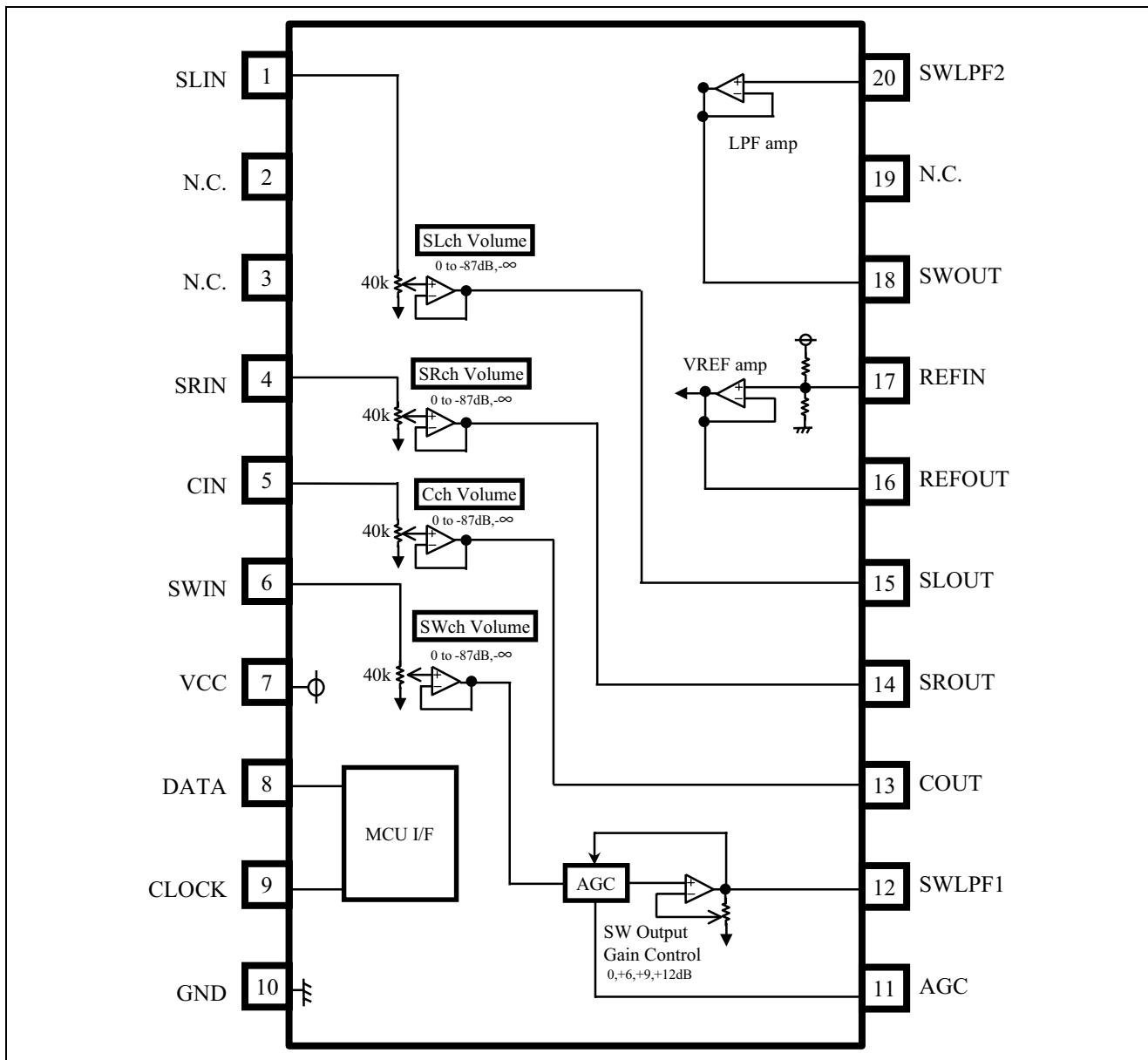
### Recommended Operating Condition

Supply Voltage Range    VCC= 8 to 10V Typ:VCC=9V

### System Block Diagram



## Block Diagram and Pin Configuration (Top view)



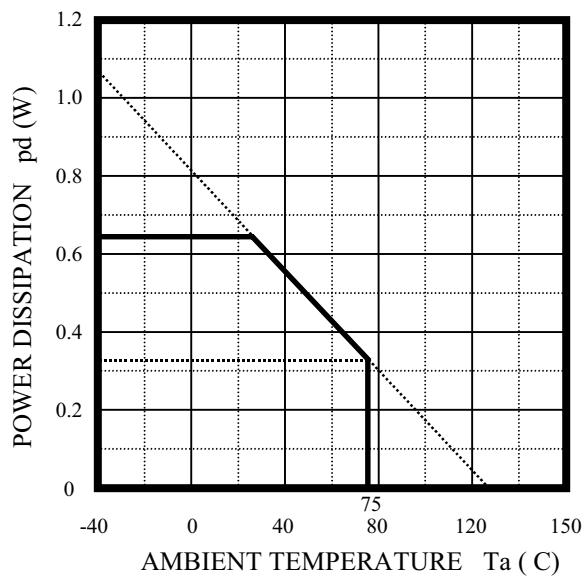
## Pin Description

Pin No.	Name	Function
1	SLIN	SLch volume input pin
2	N.C.	N.C.
3	N.C.	N.C.
4	SRIN	SRch volume input pin
5	CIN	Cch volume input pin
6	SWIN	SWch volume input pin
7	VCC	Power supply (Typ:9V)
8	DATA	Input pin of Control data
9	CLOCK	Input pin of Control clock
10	GND	Ground
11	AGC	Attack/Recovery time control pin (by capacitor)
12	SWLPF1	SWch LPF (connected with resistance and capacitor)
13	COUT	Cch output pin
14	SROUT	SRch output pin
15	SLOUT	SLch output pin
16	REFOUT	Vref output pin
17	REFIN	Vref input pin
18	SWOUT	SWch output pin
19	N.C.	N.C.
20	SWLPF2	SWch LPF (connected with resistance and capacitor)

## Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit	Condition
Power Supply	Vcc	10.5	V	
Power dissipation	Pd	648	mW	Ta ≤ 25°C
Thermal derating	Kθ	6.48	mW/°C	Ta > 25°C
Operating temperature	Topr	-20 to 75	°C	
Storage temperature	Tstg	-40 to 125	°C	

THERMAL DERATINGS  
(MAXIMUM RATING)

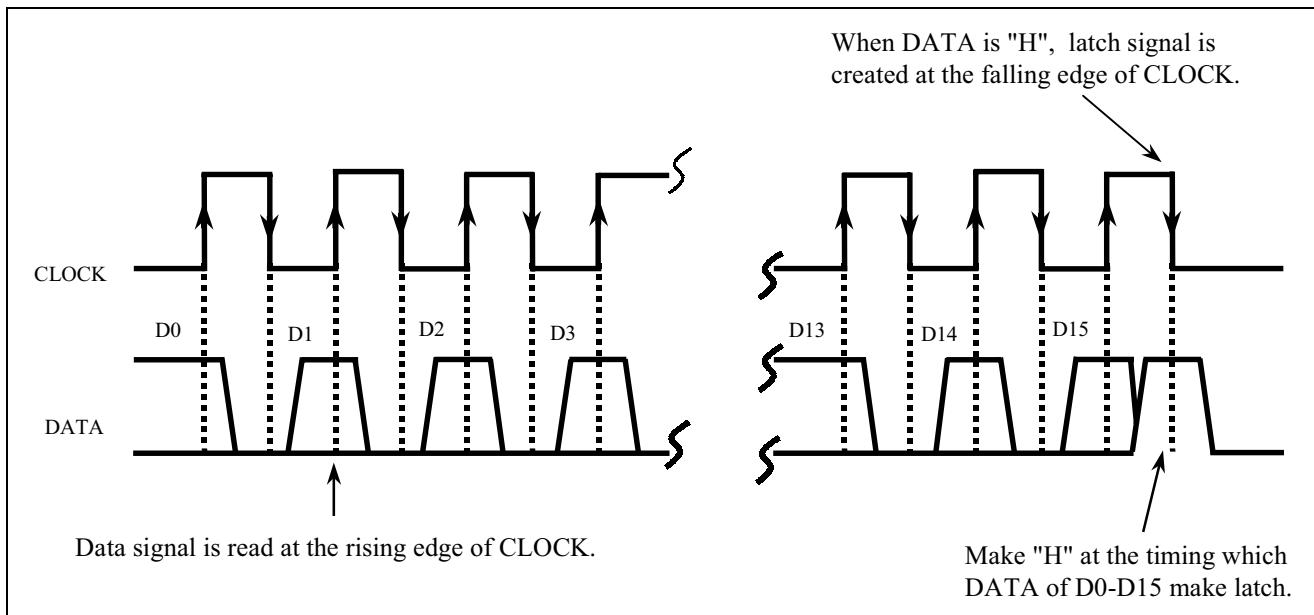


## Recommended Conditions

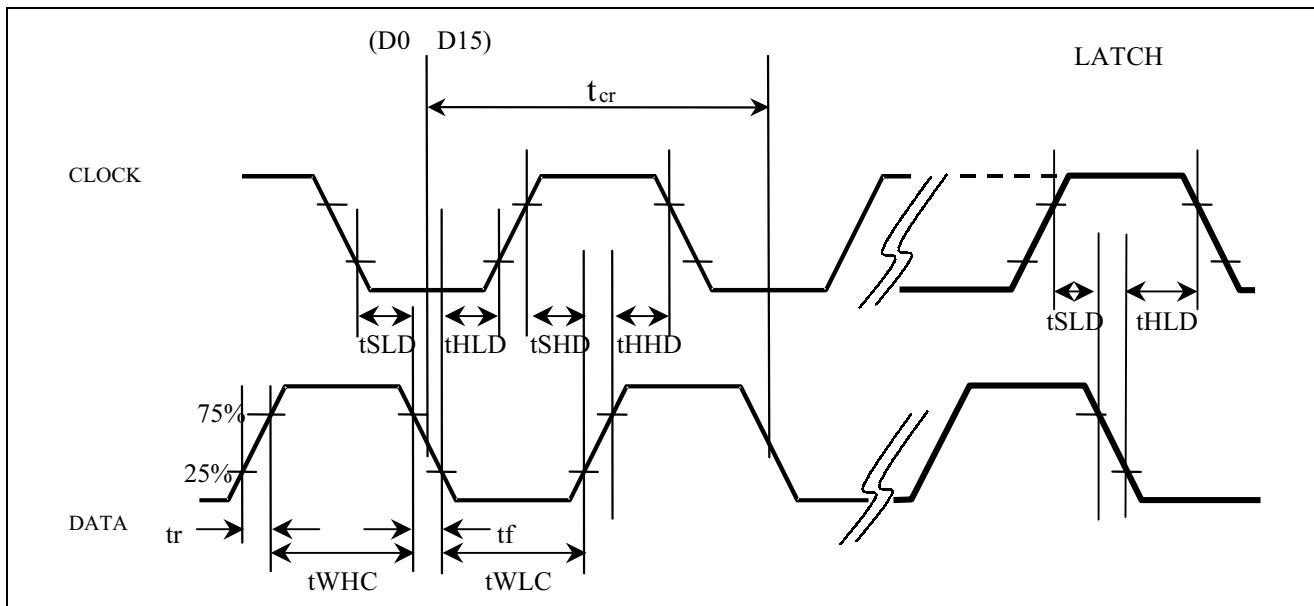
(Ta=25°C, Unless otherwise noted)

Parameter	Symbol	Limits			Unit	Conditions
		Min.	Typ.	Max.		
Power supply	Vcc	8	9	10	V	
Logic "H" level input voltage	VIH	2.2	—	5.5	V	VCC=9V GND reference
Logic "L" level input voltage	VIL	0	—	0.6	V	VCC=9V GND reference

## Relationship Between Data and Clock



## Clock and Data Timings



## Timing Definition of Digital Block

Parameter	Symbol	Limits			Unit
		Min.	Typ.	Max.	
CLOCK cycle time	tcr	4	—	—	μs
CLOCK pulse width("H" level)	tWHC	1.6	—	—	
CLOCK pulse width ("L" level)	tWLC	1.6	—	—	
Rising time of clock and data	tr	—	—	0.4	
Falling time of clock and data	tf	—	—	0.4	
DATA setup time (Rising time of clock)	tSHD	0.8	—	—	
DATA setup time (Falling time of clock)	tSLD	0.8	—	—	
DATA hold time("H" level)	tHHD	0.8	—	—	
DATA hold time("L" level)	tHLD	0.8	—	—	

## Data Control Specification

Four types of input format can be selected by changing the D14/D15 slot setting status.

(Initialize all data of the 4 formats when power supply(VCC) turn on.)

Note : No guarantee except for these code.

(1)	D0a   D1a   D2a   D3a   D4a   D5a   D6a   D7a   D8a   D9a   D10a   D11a   D12a   D13a   D14   D15	② SLch Trim volume	② SRch Trim volume	0   0   0   0   0   1   0   0	
(2)	D0b   D1b   D2b   D3b   D4b   D5b   D6b   D7b   D8b   D9b   D10b   D11b   D12b   D13b   D14   D15	② Cch Trim volume	② SWch Trim volume	1   ① SWch Output gain control   0   0   0   0   1	
(3)	D0c   D1c   D2c   D3c   D4c   D5c   D6c   D7c   D8c   D9c   D10c   D11c   D12c   D13c   D14   D15	③ SLch Master volume	③ SRch Master volume	0   0   0   0   1   0	
(4)	D0d   D1d   D2d   D3d   D4d   D5d   D6d   D7d   D8d   D9d   D10d   D11d   D12d   D13d   D14   D15	③ Cch Master volume	③ SWch Master volume	0   0   0   0   1   1	

**Setting Code**

 It's initial setting when VCC turn on.

① SWch Output gain control

	D9b	D10b
0dB	0	0
+6dB	0	1
+9dB	1	0
+12dB	1	1

② SL/SR/C/SWch Trim volume

ATT	SLch	D0a	D1a	D2a	D3a
	SRch	D4a	D5a	D6a	D7a
	Cch	D0b	D1b	D2b	D3b
	SWch	D4b	D5b	D6b	D7b
0dB	0	0	0	0	
-1dB	0	0	0	1	
-2dB	0	0	1	0	
-3dB	0	0	1	1	
-4dB	0	1	0	0	
-5dB	0	1	0	1	
-6dB	0	1	1	0	
-7dB	0	1	1	1	
-8dB	1	0	0	0	
-9dB	1	0	0	1	
-10dB	1	0	1	0	
-11dB	1	0	1	1	
-12dB	1	1	0	0	
-13dB	1	1	0	1	
-14dB	1	1	1	0	
-15dB	1	1	1	1	

③ SL/SR/C/SWch Master volume

ATT	SLch	D0c	D1c	D2c	D3c	D4c
	SRch	D5c	D6c	D7c	D8c	D9c
	Cch	D0d	D1d	D2d	D3d	D4d
	SWch	D5d	D6d	D7d	D8d	D9d
0dB	0	0	0	0	0	0
-2dB	0	0	0	0	1	
-4dB	0	0	0	1	0	
-6dB	0	0	0	1	1	
-8dB	0	0	1	0	0	
-10dB	0	0	1	0	1	
-12dB	0	0	1	1	0	
-14dB	0	0	1	1	1	
-16dB	0	1	0	0	0	
-18dB	0	1	0	0	1	
-20dB	0	1	0	1	0	
-22dB	0	1	0	1	1	
-24dB	0	1	1	0	0	
-26dB	0	1	1	0	1	
-28dB	0	1	1	1	0	
-30dB	0	1	1	1	1	
-32dB	1	0	0	0	0	
-34dB	1	0	0	0	1	
-36dB	1	0	0	1	0	
-38dB	1	0	0	1	1	
-40dB	1	0	1	0	0	
-42dB	1	0	1	0	1	
-44dB	1	0	1	1	0	
-48dB	1	0	1	1	1	
-52dB	1	1	0	0	0	
-56dB	1	1	0	0	1	
-60dB	1	1	0	1	0	
-64dB	1	1	0	1	1	
-68dB	1	1	1	0	0	
-72dB	1	1	1	0	1	
-76dB	1	1	1	1	0	
-∞ dB	1	1	1	1	1	

Note1: Volume ATT controlled by trim volume data + master volume data.

Note2: When trim volume data + master volume data is under -87dB setting , volume ATT keep -87dB.

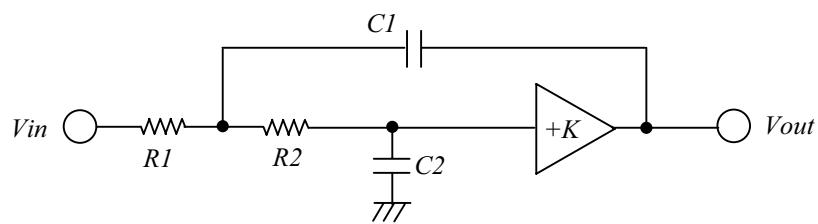
ex) When trim volume data:-15dB / master volume data -76dB setting , volume ATT keep -87dB.

**Electrical characteristics**

Unless otherwise noted, Ta=25°C, Vcc=9V, f=1kHz, Trim/Master Volume=0dB, Output Gain Control=0dB, SWch LPF fc=300Hz

Parameter	Symbol	Limits				Test conditions
		Min.	Typ.	Max.	Unit	
Power circuit current	IACC	—	15	30	mA	when no signal is provided
Input/output						
Maximum input voltage	VIM	—	—	2.0*	Vrms	(1,4,5,6)PIN input,(13,14,15,18)PIN output, RL=10kΩ, THD=1%
Maximum output voltage	VOM1	1.4	1.8	—	Vrms	6PIN input, 18PIN output, RL=10kΩ, THD=5% , f=100Hz
	VOM2	1.6	2.0	—	Vrms	(1,4,5)PIN input , (13,14,15)output, RL=10kΩ, THD=5%
Pass gain	GV	-2	0	+2	dB	(1,4,5,6)PIN input, (13,14,15,18) output, Vi=0.5Vrms, FLAT
Output noise voltage	Vno1	—	1.3	4.0	μVrms	JIS-A, when no signal is provided, (1,4,5)PIN Rg=0 Ω, (13,14,15)PIN output
		—	1.3	4.0	μVrms	SL/SR/Cch volume =0dB
	Vno2	—	8.0	16	μVrms	JIS-A, when no signal is provided, 6PIN Rg=0 Ω, 18PIN output,
		—	8.0	16	μVrms	SWch volume =0dB
Distortion	THD1	—	0.005	0.1	%	(1,4,5)PIN input, (13,14,15)output, BW:400 30kHz, Vo=0.5Vrms, RL=10kΩ
	THD2	—	0.05	0.2	%	6PIN input,12PIN output, 30kHz L.P.F, f=100Hz, Output Gain Control =0dB, Vi=0.5Vrms(AGC:off), RL=10kΩ
	THD3	—	5	—	%	6PIN input, 12PIN output, 30kHz L.P.F, f=100Hz, Output Gain Control =+12dB, Vi=0.7Vrms(AGC:on), RL=10kΩ
Maximum attenuation	ATT	—	-92	-87	dB	Vo=1Vrms, (12,13,14,15) PIN output, JIS-A, VOL=-∞
Maximum gain	GVM	+10	+12	+14	dB	6PIN input, 12PIN output, f=100Hz, Vi=0.1Vrms, FLAT, Output Gain Control =+12dB
Cross talk between channels	CT	—	-70	-55	dB	(1,4,5,6)PIN input, (12,13,14,15)PIN output, Vi=0.5Vrms, JIS-A, RL=47kΩ, Rg=0kΩ
AGC						
Attack time	TAGCAT	—	40	—	ms	6PIN input, 12PIN output, RL=10kΩ, Output Gain Control =+12dB
Recovery time	TAGCRE	—	850	—	ms	6PIN input, 12PIN output, RL=10kΩ, Output Gain Control =+12dB

\* Note : The signal can not be inputted to more than 2Vrms. Keep this limit.

**LPF****Equivalent circuit of LPF**

$$F(s) = \frac{V_{out}}{V_{in}} = \frac{\frac{1}{R_1 R_2 C_1 C_2} K}{S^2 + \left[ \frac{1}{R_1 C_1} + \frac{1}{R_2 C_1} + (1-K) \frac{1}{R_2 C_2} \right] S + \frac{1}{R_1 R_2 C_1 C_2}}$$

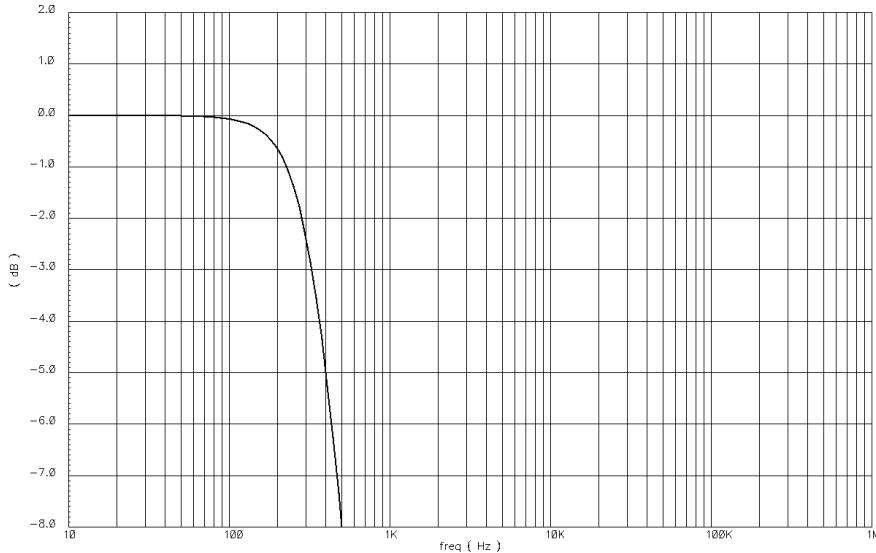
$$\omega_0 = \sqrt{\frac{1}{R_1 R_2 C_1 C_2}} \quad Q = \frac{1}{\sqrt{\frac{R_2 C_2}{R_1 C_1}} + \sqrt{\frac{R_1 C_2}{R_2 C_1}} + (1-K) \sqrt{\frac{R_1 C_1}{R_2 C_2}}}$$

**Frequency characteristics (SWch LPF)**

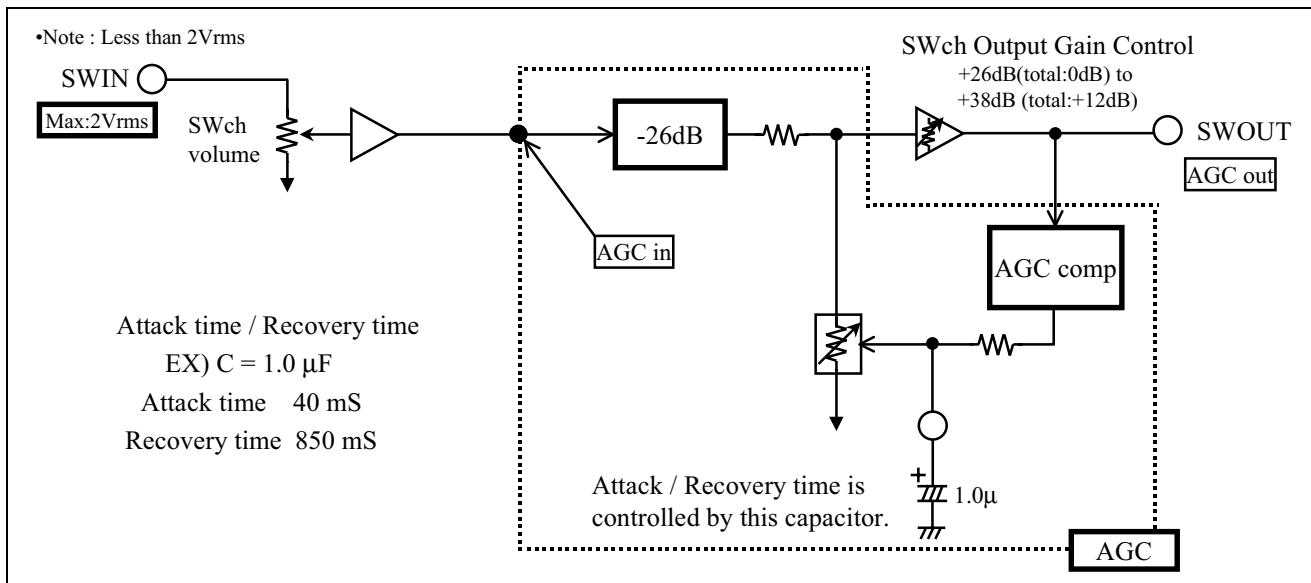
R1=2.2kΩ, R2=4.7kΩ, C1=0.22μF, C2= 0.1μF, K=1

Q ≈ 0.68, fc ≈ 300Hz

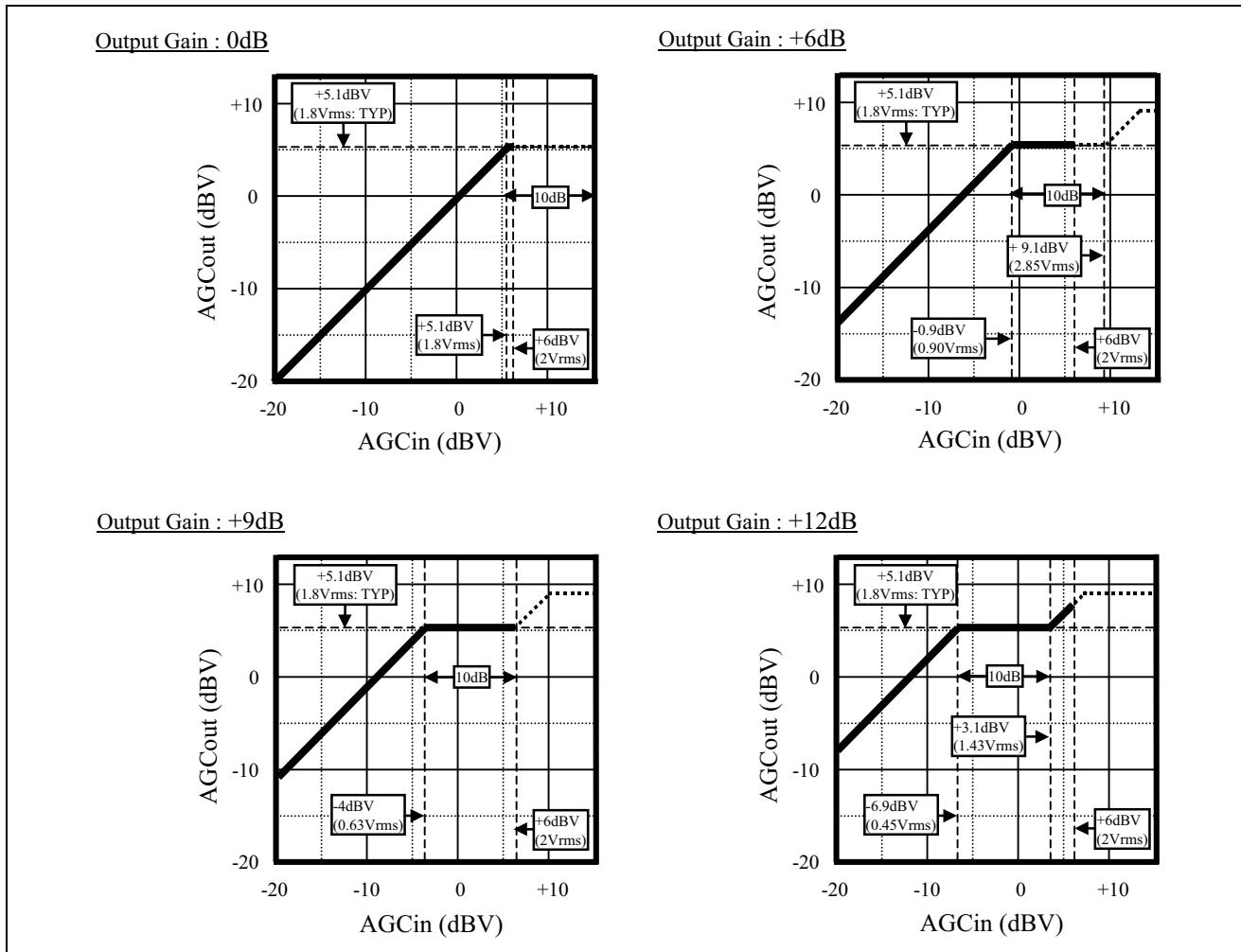
\*This frequency response is a simulation result.



## AGC

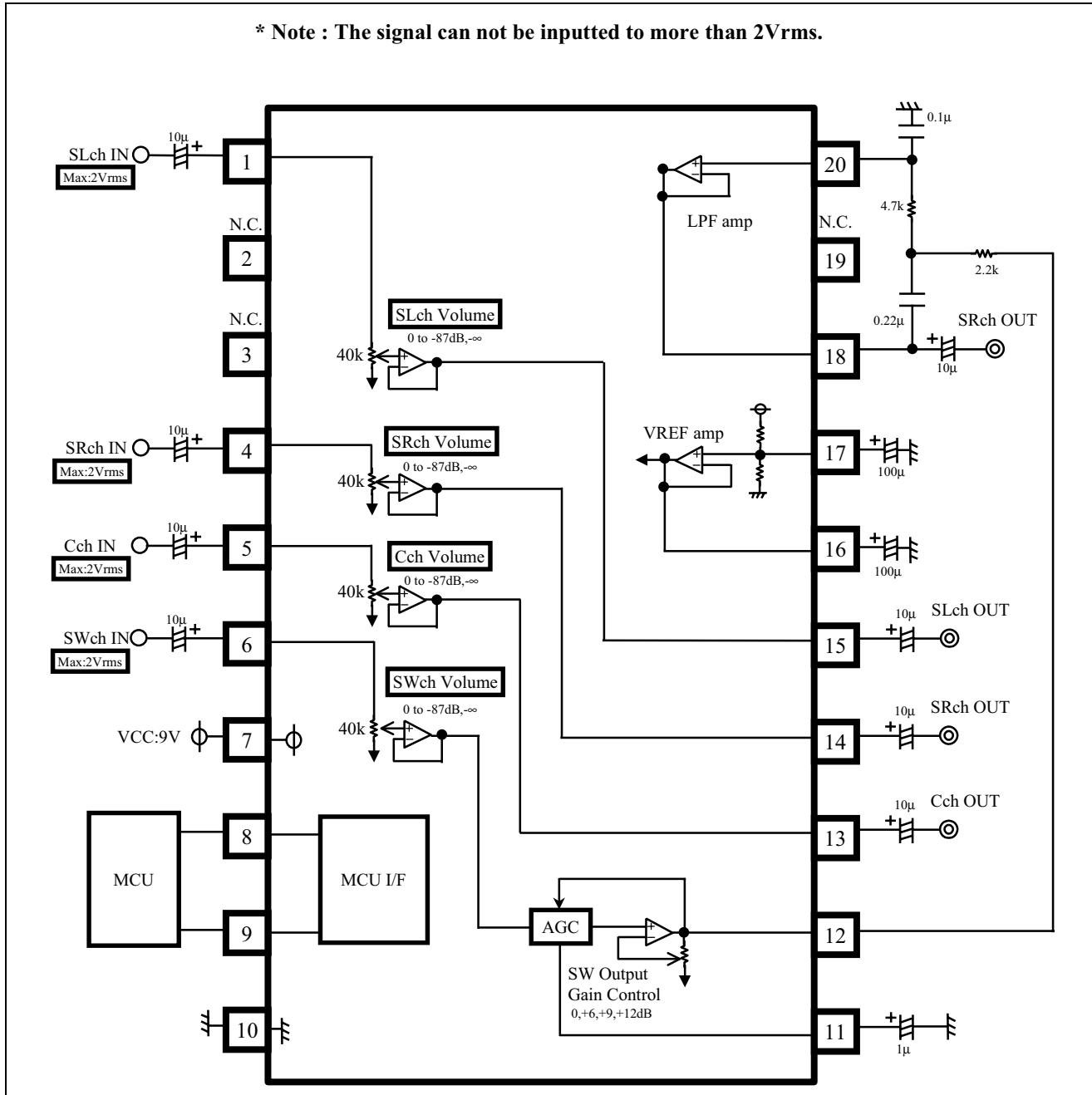


## AGC characteristics

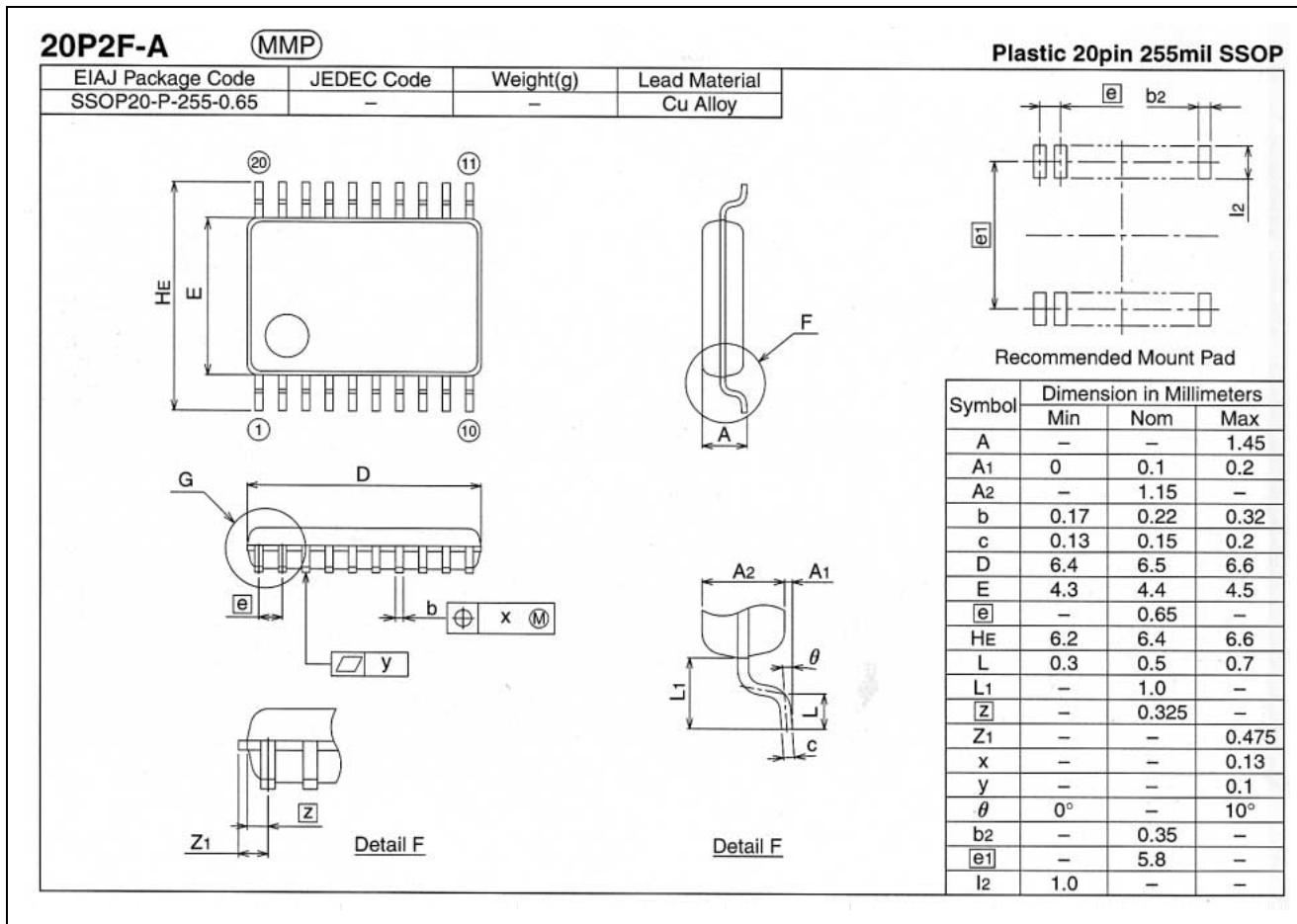


## Application Example

\* Note : The signal can not be inputted to more than 2Vrms.



## Package Dimensions



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